

$V_{DSS}$	-45V
$R_{DS(on)}$ (Max.)	155mΩ
$I_D$	-4.5A
$P_D$	15W

### ●Features

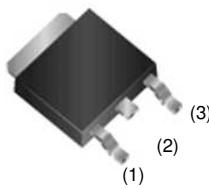
- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating ; RoHS compliant
- 6) 100% Avalanche tested

### ●Application

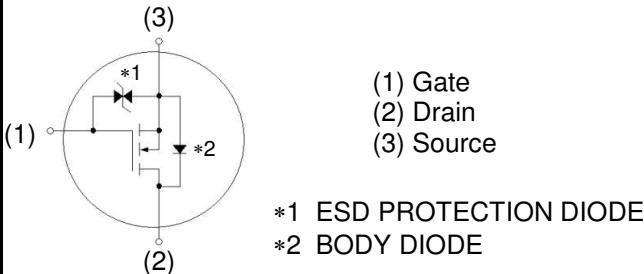
Switching Power Supply  
 Automotive Motor Drive  
 Automotive Solenoid Drive

### ●Outline

CPT3  
 (SC-63)  
 <SOT-428>



### ●Inner circuit



### ●Packaging specifications

Type	Packaging	Taping
	Reel size (mm)	330
	Tape width (mm)	16
	Basic ordering unit (pcs)	2,500
	Taping code	TL
	Marking	046P05

### ●Absolute maximum ratings( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Drain - Source voltage	$V_{DSS}$	-45	V
Continuous drain current	$I_D$ * <sup>1</sup> $T_c = 25^\circ\text{C}$	$\pm 4.5$	A
	$I_D$ * <sup>1</sup> $T_c = 100^\circ\text{C}$	$\pm 2.4$	A
Pulsed drain current	$I_{D,pulse}$ * <sup>2</sup>	$\pm 9.0$	A
Gate - Source voltage	$V_{GSS}$	$\pm 20$	V
Avalanche energy, single pulse	$E_{AS}$ * <sup>3</sup>	14.3	mJ
Avalanche current	$I_{AR}$ * <sup>3</sup>	-4.5	A
Power dissipation	$P_D$ $T_c = 25^\circ\text{C}$	15	W
	$P_D$ $T_a = 25^\circ\text{C}$ * <sup>4</sup>	0.85	W
Junction temperature	$T_j$	150	°C
Range of storage temperature	$T_{stg}$	-55 to +150	°C

### ● Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - ambient	R <sub>thJC</sub>	-	-	8.33	°C/W
Thermal resistance, junction - ambient <sup>*4</sup>	R <sub>thJA</sub>	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

### ● Electrical characteristics (T<sub>a</sub> = 25 °C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = -1mA	-45	-	-	V
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = -45V, V <sub>GS</sub> = 0V T <sub>j</sub> = 25 °C	-	-	-1	μA
		V <sub>DS</sub> = -45V, V <sub>GS</sub> = 0V T <sub>j</sub> = 125 °C	-	-	-100	
Gate - Source leakage current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V	-	-	±10	μA
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = -10V, I <sub>D</sub> = -1mA	-1	-	-3	V
Static drain - source on - state resistance <sup>*5</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10V, I <sub>D</sub> = -4.5A	-	110	155	mΩ
		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -4.5A	-	160	225	
		V <sub>GS</sub> = -4.0V, I <sub>D</sub> = -4.5A	-	185	260	
		V <sub>GS</sub> = -10V, I <sub>D</sub> = -4.5A T <sub>j</sub> = 125 °C	-	180	250	
Forward transfer admittance	g <sub>fs</sub>	V <sub>DS</sub> = -10V, I <sub>D</sub> = -4.5A	3	6	-	S

● Electrical characteristics( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	$C_{iss}$	$V_{GS} = 0\text{V}$ $V_{DS} = -10\text{V}$ $f = 1\text{MHz}$	-	550	-	pF
Output capacitance	$C_{oss}$		-	100	-	
Reverse transfer capacitance	$C_{rss}$		-	50	-	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DD} \approx -25\text{V}, V_{GS} = -10\text{V}$ $I_D = -2.0\text{A}$ $R_L = 12\Omega$ $R_G = 10\Omega$	-	8	-	ns
Rise time	$t_r^{*5}$		-	8	-	
Turn - off delay time	$t_{d(off)}^{*5}$		-	35	-	
Fall time	$t_f^{*5}$		-	8	-	

● Gate Charge characteristics( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	$Q_g^{*5}$	$V_{DD} \approx -25\text{V}$ $I_D = -4.5\text{A}$ $V_{GS} = -5\text{V}$	-	12	-	nC
Gate - Source charge	$Q_{gs}^{*5}$		-	2.2	-	
Gate - Drain charge	$Q_{gd}^{*5}$		-	2.2	-	
Gate plateau voltage	$V_{(plateau)}$	$V_{DD} \approx -30\text{V}, I_D = -4.5\text{A}$	-	-3.4	-	V

● Body diode electrical characteristics (Source-Drain)( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Continuous source current	$I_S^{*1}$	$T_c = 25^\circ\text{C}$	-	6	-4.5	A
Pulsed source current	$I_{SM}^{*2}$		-	-	-9	A
Forward voltage	$V_{SD}^{*5}$	$V_{GS} = 0\text{V}, I_S = -4.5\text{A}$	-	-	-1.2	V
Reverse recovery time	$t_{rr}^{*5}$	$I_S = -4.5\text{A}$ $di/dt = -100\text{A}/\mu\text{s}$	-	40	-	ns
Reverse recovery charge	$Q_{rr}^{*5}$		-	60	-	$\mu\text{C}$

\*1 Limited only by maximum temperature allowed.

\*2  $P_w \leq 10\mu\text{s}$ , Duty cycle  $\leq 1\%$

\*3  $L \approx 1\text{mH}$ ,  $V_{DD} = -25\text{V}$ ,  $R_G = 10\Omega$ , starting  $T_j = 25^\circ\text{C}$

\*4 Mounted on a epoxy PCB FR4 (20mm × 30mm × 0.8mm)

\*5 Pulsed

## ● Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

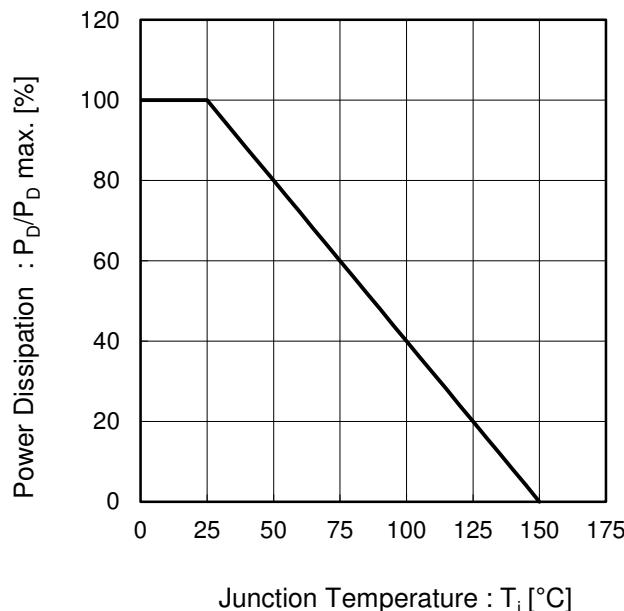


Fig.2 Maximum Safe Operating Area

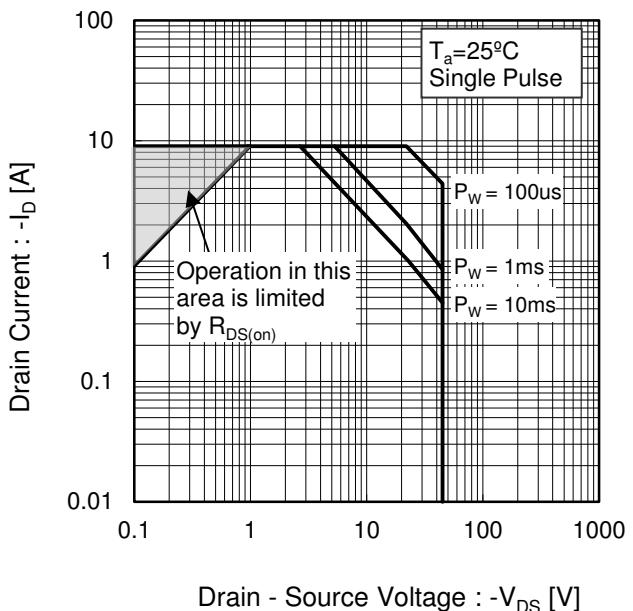
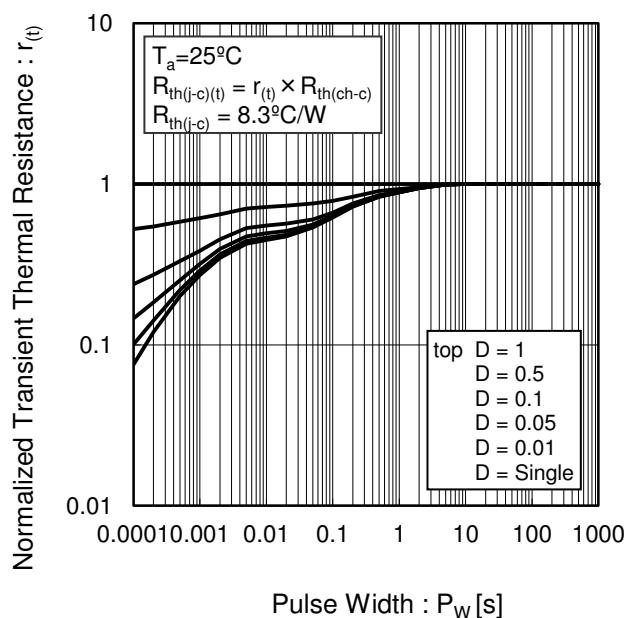


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



● Electrical characteristic curves

Fig.4 Avalanche Current vs Inductive Load

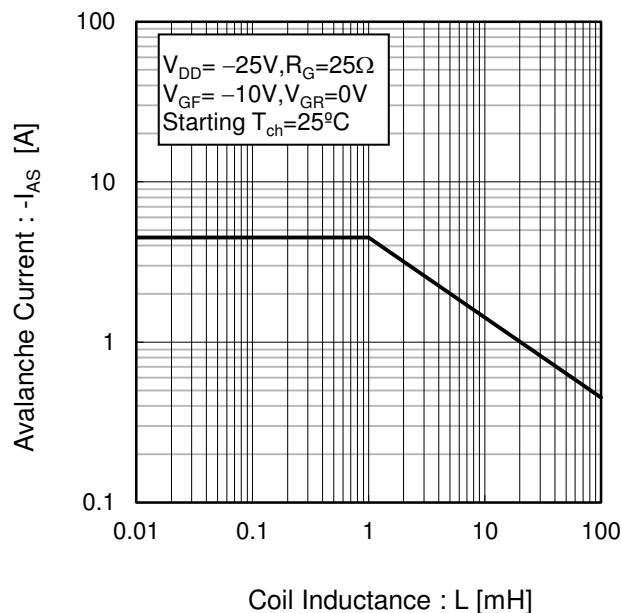


Fig.5 Avalanche Energy Derating Curve vs Junction Temperature

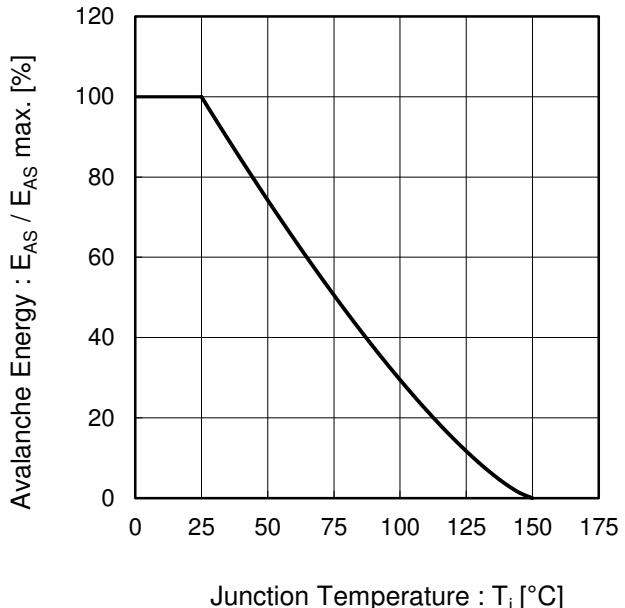


Fig.6 Typical Output Characteristics(I)

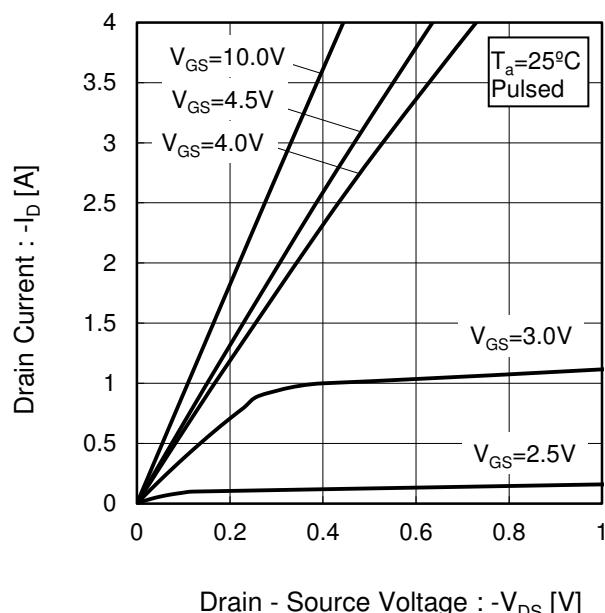
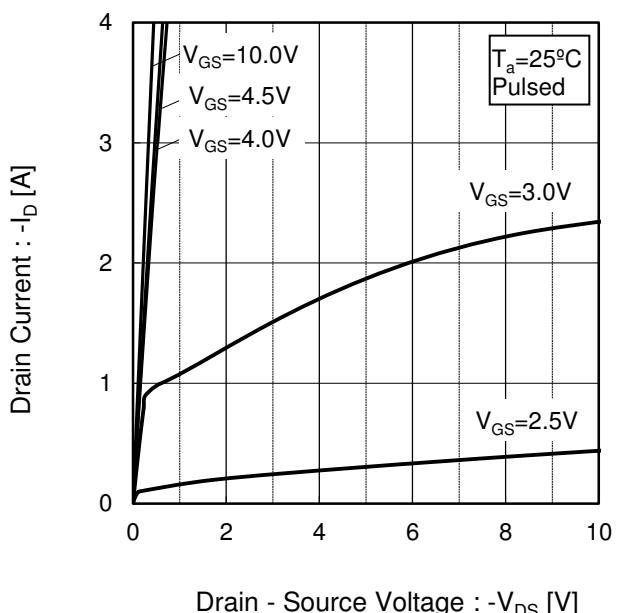


Fig.7 Typical Output Characteristics(II)



● Electrical characteristic curves

Fig.8 Breakdown Voltage  
vs. Junction Temperature

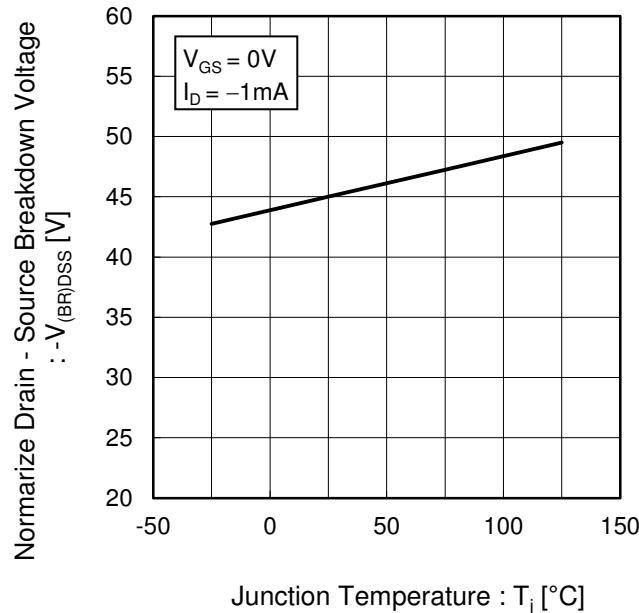


Fig.9 Typical Transfer Characteristics

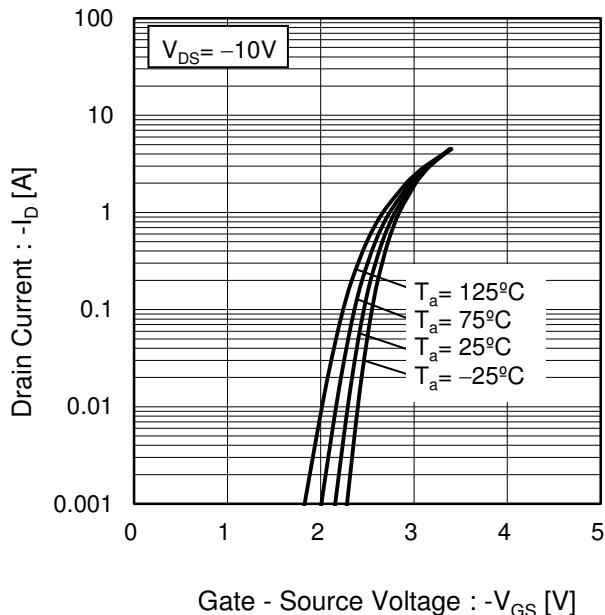


Fig.10 Gate Threshold Voltage  
vs. Junction Temperature

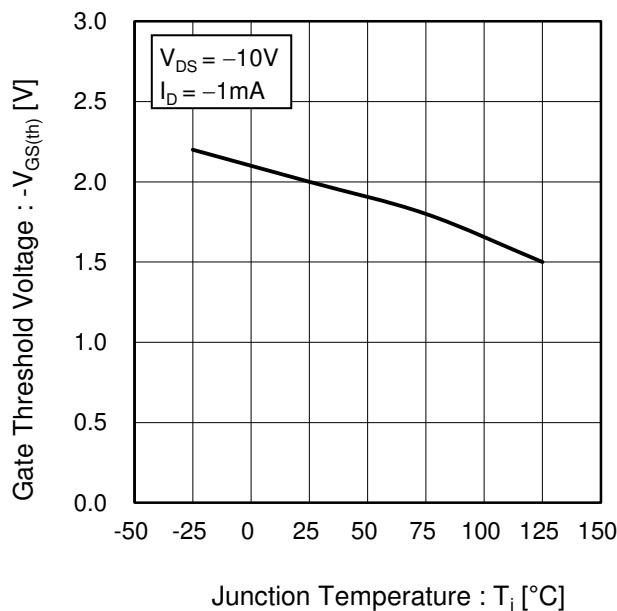
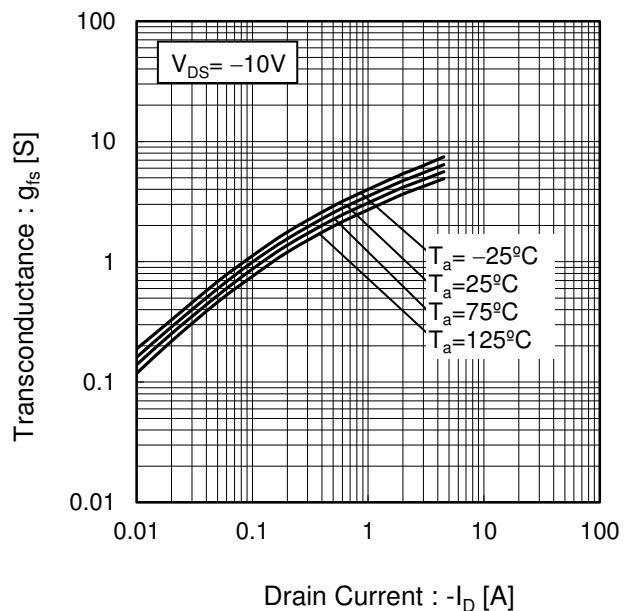


Fig.11 Transconductance vs. Drain Current



● Electrical characteristic curves

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

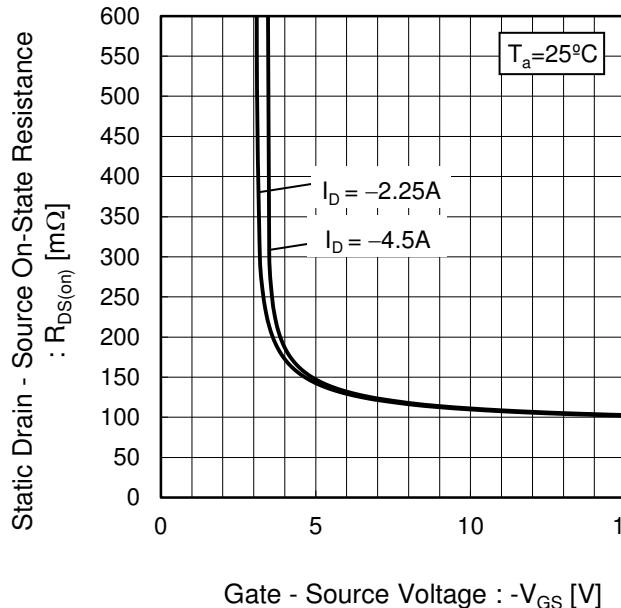


Fig.13 Static Drain - Source On - State Resistance vs. Drain Current( $I_D$ )

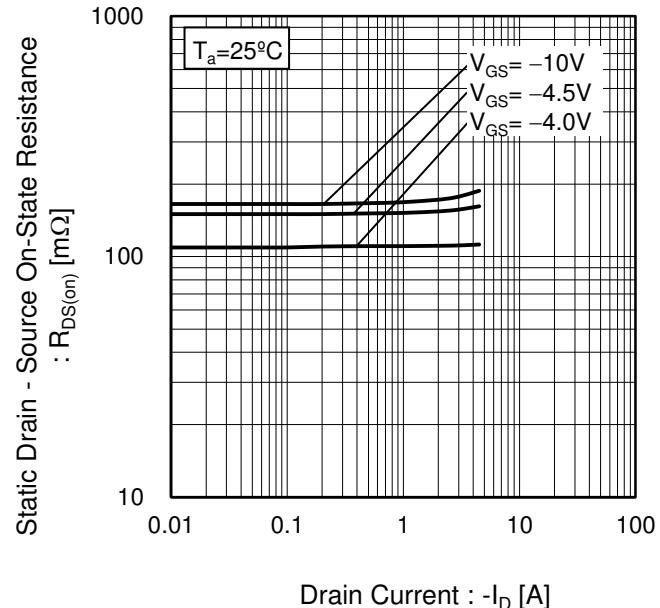
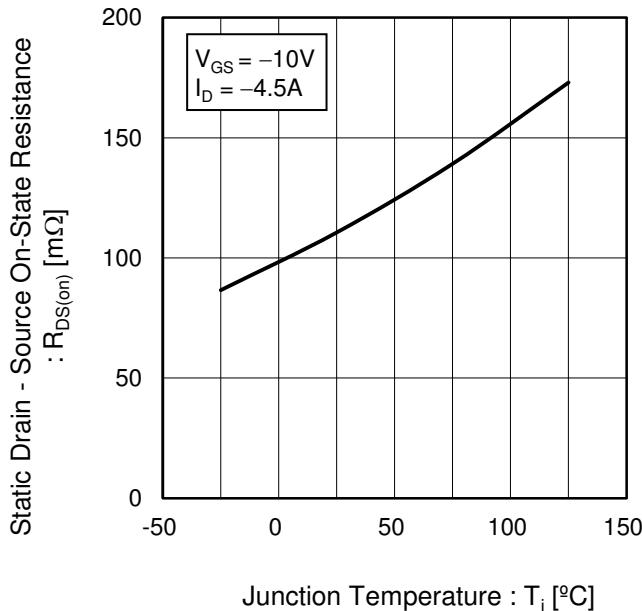


Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature



● Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

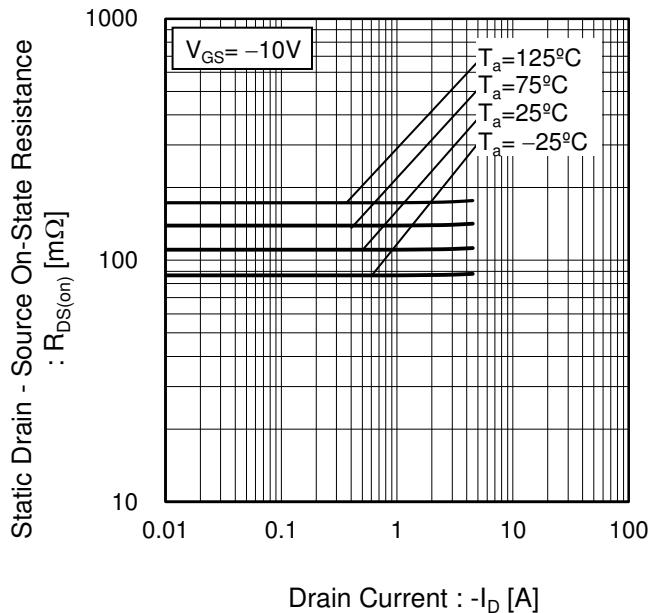


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

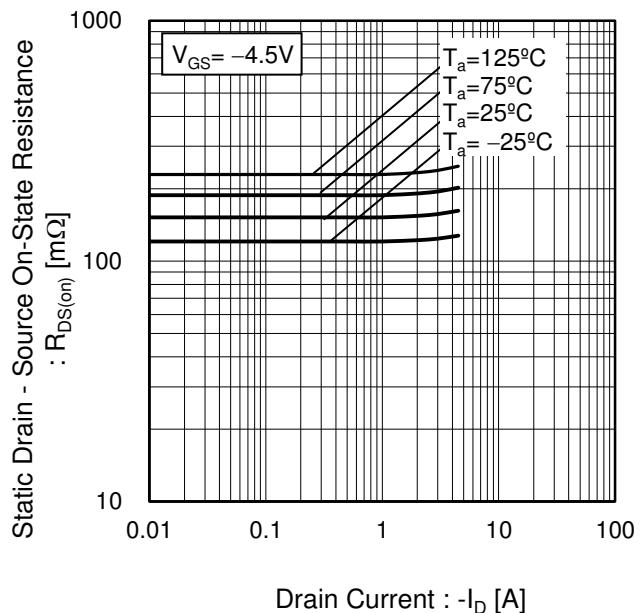


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)

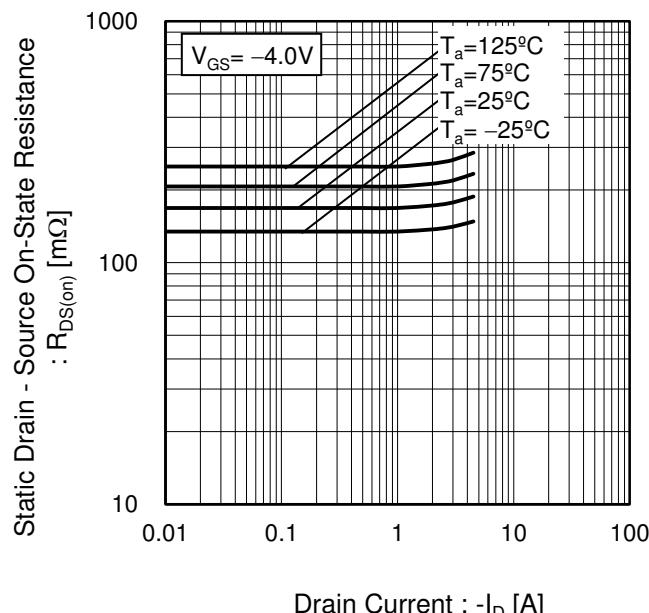
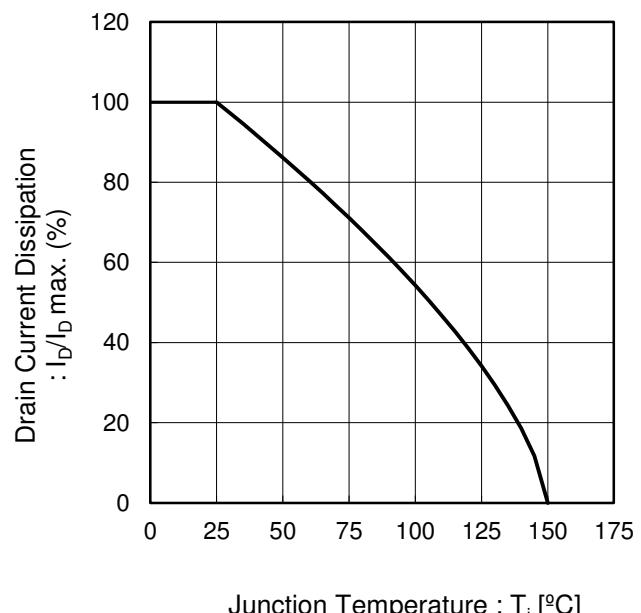


Fig.18 Drain Current Derating Curve



● Electrical characteristic curves

Fig.19 Typical Capacitance vs. Drain - Source Voltage

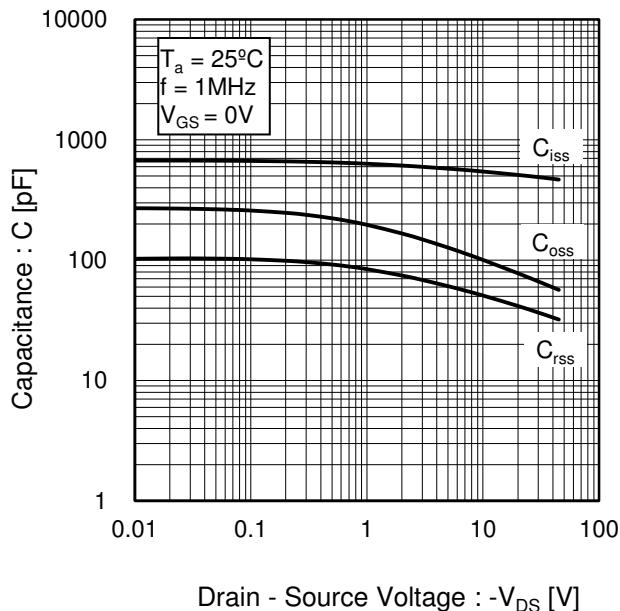


Fig.20 Switching Characteristics

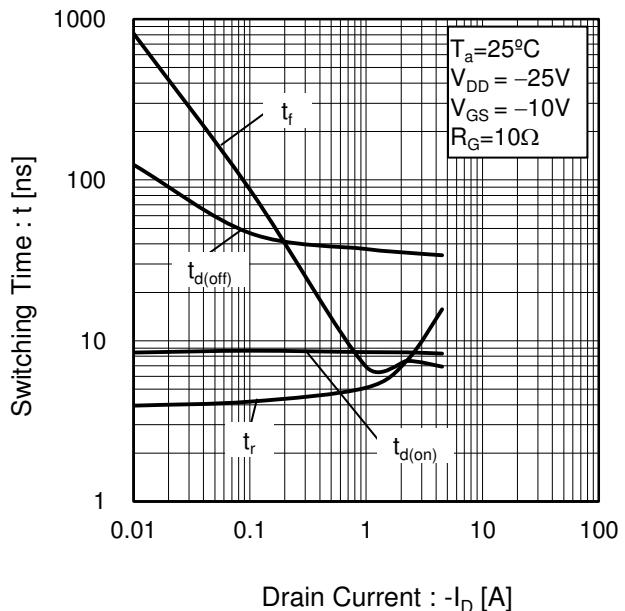


Fig.21 Dynamic Input Characteristics

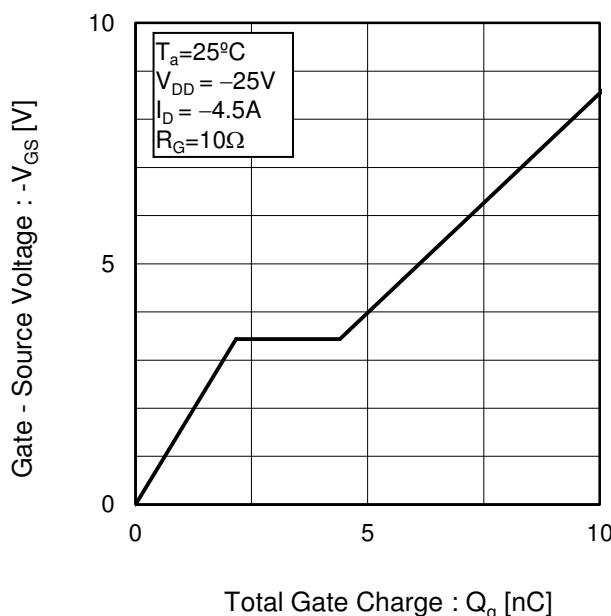
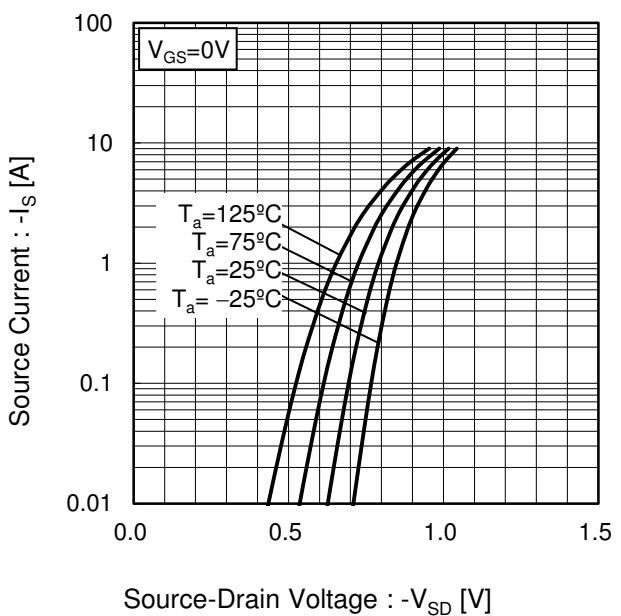
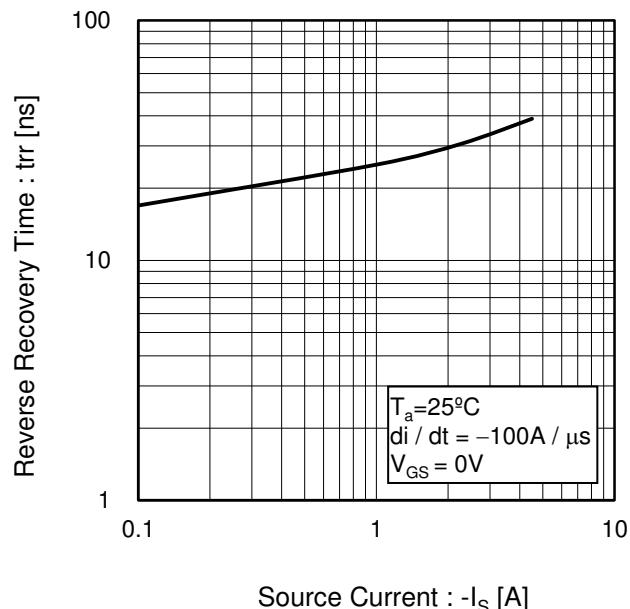


Fig.22 Source Current vs. Source - Drain Voltage



**●Electrical characteristic curves**Fig23 Reverse Recovery Time  
vs. Source Current

## ● Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

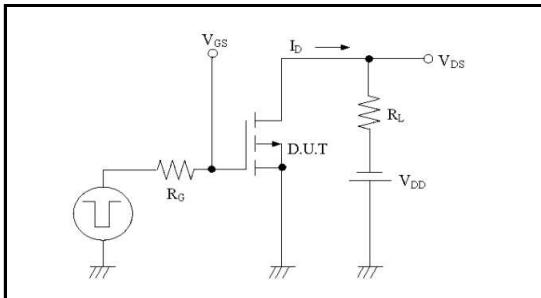


Fig.1-2 Switching Waveforms

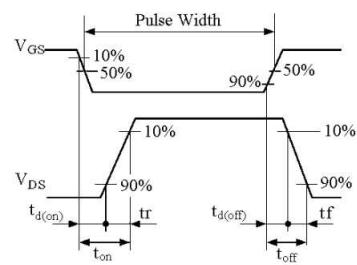


Fig.2-1 Gate Charge Measurement Circuit

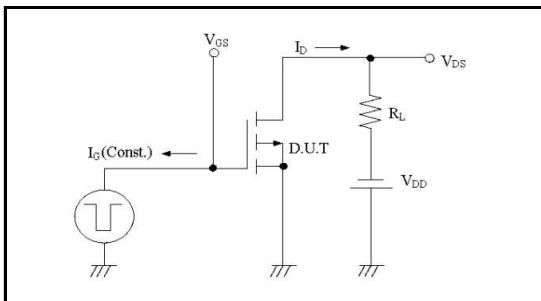


Fig.2-2 Gate Charge Waveform

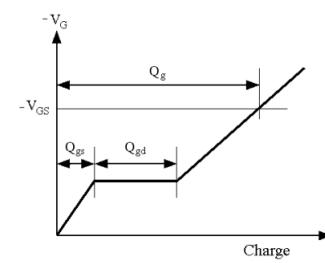


Fig.3-1 Avalanche Measurement Circuit

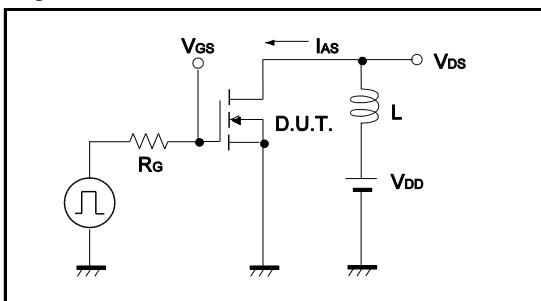
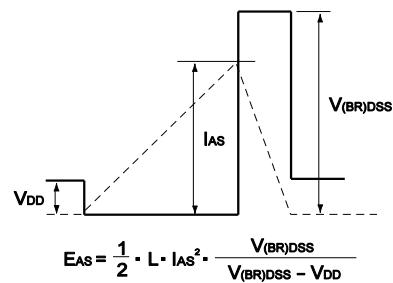
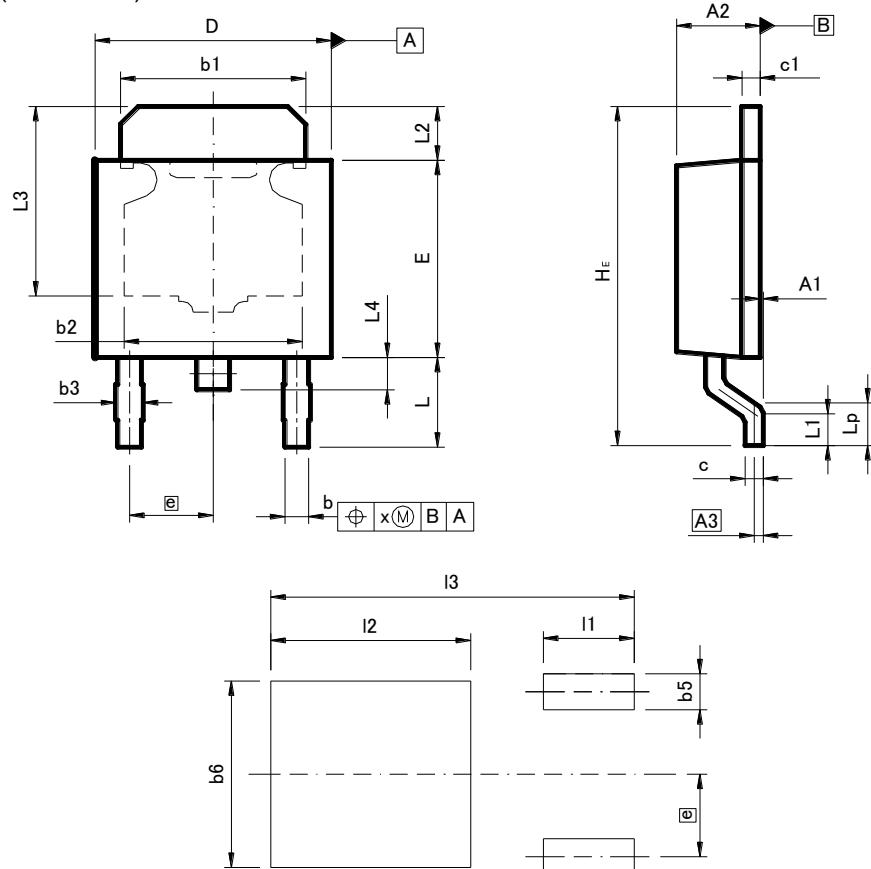


Fig.3-2 Avalanche Waveform



●Dimensions (Unit : mm)

CPT3



DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A1	0.00	0.15	0	0.006
A2	2.20	2.50	0.087	0.098
A3	0.25		0.01	
b	0.55	0.75	0.022	0.03
b1	5.00	5.30	0.197	0.209
b2	5.00		0.20	
b3	0.75		0.03	
c	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
e	2.30		0.09	
H_E	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.11
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.30		0.209	
L4	0.90		0.035	
Lp	1.00	1.60	0.039	0.063
x	-	0.25	-	0.01

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b5	-	1.00	-	0.04
b6	-	5.20	-	0.205
I1	-	2.50	-	0.098
I2	-	5.50	-	0.217
I3	-	10.00	-	0.394

Dimension in mm/inches

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